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| <b>Notice of References Cited</b> | Application/Control No.<br>10/787,133 |  | Applicant(s)/Patent Under Reexamination<br>KAJIYAMA, TAKESHI |             |
|                                   | Examiner<br>Evan Pert                 |  | Art Unit<br>2826   | Page 1 of 1 |

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Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.